NSN 5961-00-021-9057

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View Online at https://aerobasegroup.com/nsn/5961-00-021-9057 **Inclosure Material:** Metal **Overall Length:** 0.260 inches **Terminal Length:** 1.500 inches **Overall Diameter:** 0.370 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Collector **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 60.0 collector to base voltage/static/emitter open all transistor and 40.0 collector to emitter voltage/static/base open all transistor and 5.0 breakdown voltage, emitter-to-base, collector open all transistor **Current Rating Per Characteristic:** 10.00 microamperes source cutoff current all transistor **Power Rating Per Characteristic:** 3.0 watts small-signal input power, common-collector absolute all transistor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** All transistor junction pattern arrangement: npn **Precious Material And Location:** Terminal surfaces gold **Precious Material:** Gold **Terminal Type And Quantity:** 6 uninsulated wire lead Shelf Life:

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N/a

Unit Of Measure:

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Demilitarization:

No

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